

Diode - Small Signal

MMBD1501A, MMBD1503A, MMBD1504A, MMBD1504A

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Notes 1, 2)

Symbol	Pai	Value	Unit		
V_{RRM}	Maximum Repetiti	200	V		
I _{F(AV)}	Average Rectified Forward Current		200	mA	
I _{FSM}	Non-Repetitive Peak Forward	Pulse Width = 1.0 s	1.0	Α	
	Surge Current	Pulse Width = 1.0 μs	2.0		
T _{STG}	Storage Temperat	-55 to +150	°C		
T_J	Operating Junction	-55 to +150	°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS

(Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	°C/W

ELECTRICAL CHARACTERISTICS

(Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	Breakdown Voltage	I _R = 5.0 μA	200	ı	V
V _F	Forward Voltage	I _F = 1.0 mA	620	720	mV
		I _F = 10 mA	720	830	mV
		I _F = 50 mA	800	890	mV
		I _F = 100 mA	830	930	mV
		I _F = 200 mA	0.87	1.10	V
		I _F = 300 mA	0.90	1.15	V
I _R	Reverse Current	V _R = 125 V	_	1.0	nA
		V _R = 125 V, T _A = 150°C	_	3.0	μΑ
		V _R = 180 V	-	10.0	nA
		V _R = 180 V, T _A = 150°C	_	5.0	μΑ
C _T	Total Capacitance	V _R = 0, f = 1.0 MHz	_	4.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

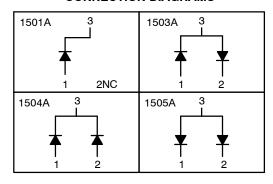






SOT-23 CASE 318BM

CONNECTION DIAGRAMS



MARKING DIAGRAM



A1x = Specific Device Code

x = 1, 3, 4, 5

M = Date Code

■ = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

MMBD1501A, MMBD1503A, MMBD1504A, MMBD1505A

TYPICAL CHARACTERISTICS

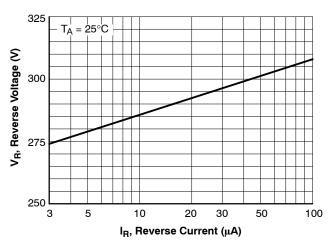


Figure 1. Reverse Voltage vs. Reverse Current I_R – 3.0 to 100 μA

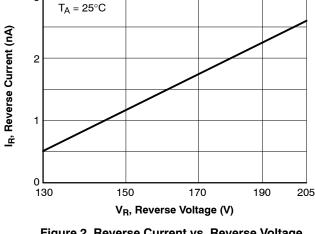


Figure 2. Reverse Current vs. Reverse Voltage V_R – 130 to 205 V

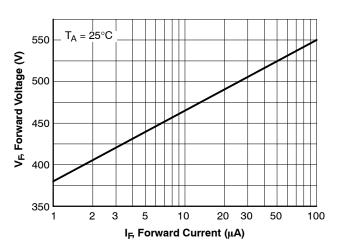


Figure 3. Forward Voltage vs. Forward Current I_F – 1 to 100 μA

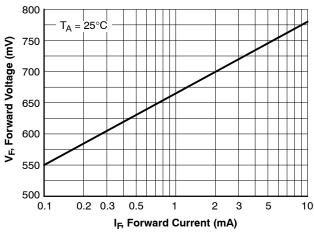


Figure 4. Forward Voltage vs. Forward Current I_F – 0.1 to 10 mA

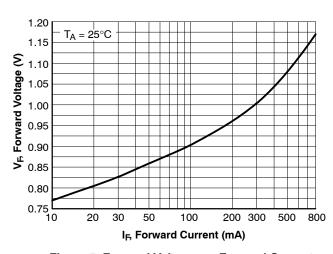


Figure 5. Forward Voltage vs. Forward Current I_F – 10 to 800 mA

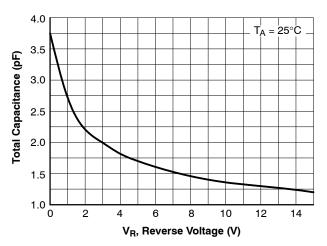


Figure 6. Total Capacitance vs. Reverse Voltage V_R – 0 to 15 V

MMBD1501A, MMBD1503A, MMBD1504A, MMBD1505A

TYPICAL CHARACTERISTICS (Continued)

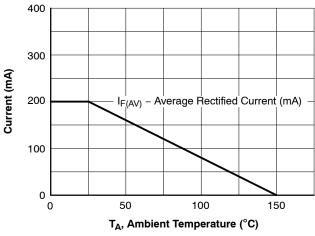


Figure 7. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

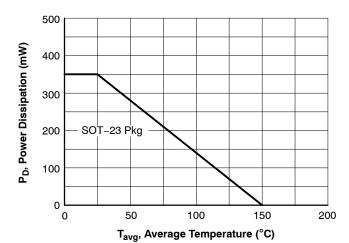


Figure 8. Power Derating Curve

ORDERING INFORMATION

Part Number	Specific Device Marking	Package Type	Shipping [†]	
MMBD1501A	A11	SOT-23 (TO-236)	3,000 / Tape & Reel (7")	
MMBD1503A	A13	(Pb-Free)		
MMBD1503A_D87Z	A13	SOT-23 (Pb-Free)	10,000 / Tape & Reel (13")	
MMBD1504A	A14	SOT-23 (TO-236)	3,000 / Tape & Reel (7")	
MMBD1505A	A15	- (Pb-Free)		
NSVMMBD1501ALT3G*	A11			
NSVMMBD1504ALT1G*	A16			

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

DATE 30 JAN 2018

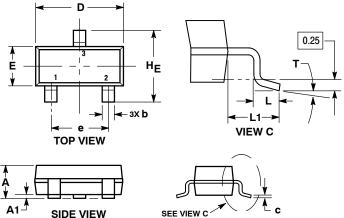
SCALE 4:1

CTVLE 4 TUDULE.

DRAIN

3. CATHODE

STYLE 27: PIN 1. CATHODE 2. CATHODE



END VIEW

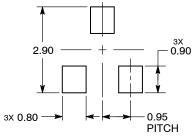
CTVLE 7

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

RECOMMENDED SOLDERING FOOTPRINT



CTVLE 6.

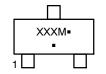
DIMENSIONS: MILLIMETERS

3. INPUT

3. ANODE

STYLE 28: PIN 1. ANODE 2. ANODE

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1 THRU 5:	STYLE 6:	STYLE 7:	STYLE 8:		
CANCELLED	PIN 1. BASE	PIN 1. EMITTER	PIN 1. ANODE		
	EMITTER	2. BASE	NO CONNECTION		
	COLLECTOR	3. COLLECTOR	3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
ANODE	SOURCE	CATHODE	CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION		PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANOD	
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
2. 300NCE	2. OUIFUI	Z. ANODE	2. DITAIN	2. OATTODE	2. ANODE

CATHODE

CTVI F O

3. SOURCE

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DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 1

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3. NO CONNECTION

3



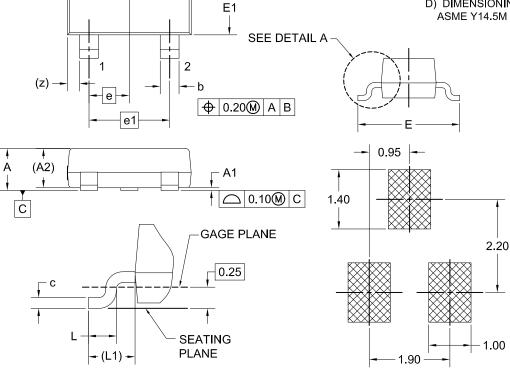


SOT-23 CASE 318BM ISSUE A

DATE 01 SEP 2021

NOTES: UNLESS OTHERWISE SPECIFIED

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M 2009.



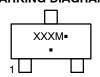
Α

В

DIM	MILLIMETERS				
Diw	MIN.	NOM.	MAX.		
Α			1.20		
A1	0.00	0.05	0.10		
A2	0).93 REF			
b	0.37	0.44	0.60		
С	0.08	0.15	0.23		
D	2.72	2.92	3.12		
Е	2.10	2.40	2.70		
E1	1.15	1.30	1.50		
е	0.95 BSC				
e1	1.90 BSC				
L	0.20				
L1	0.55 REF				
z	0.29 REF				

GENERIC
MARKING DIAGRAM*

DETAIL A



MANUAL, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may

or may not be present. Some products may

not follow the Generic Marking.

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XXX = Specific Device Code
M = Date Code

= Pb-Free Package

DOCUMENT NUMBER: 98AON13784G

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PAGE 1 OF 1

LAND PATTERN
RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR
PB-FREE STRATEGY AND SOLDERING

DETAILS, PLEASE DOWNLOAD THE ON

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